



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of:

Byung-hee KIM et al.

Group Art Unit: 2823

Serial No.: 09/800,904

Examiner: George R. FOURSON

Filed: 8 March 2001

FERROELECTRIC RANDOM ACCESS MEMORY DEVICE AND FABRICATION METHOD THEREOF

AMENDMENT UNDER 37 C.F.R. § 1.116

U.S. Patent and Trademark Office Customer Window, Mail Stop <u>AF</u> Randolph Building 401 Dulany Street Alexandria, VA 22314

Sir:

In response to the Office Action dated 14 January 2005, the period for response to which is 14 April 2005, please amend the above-identified patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 4 of this paper.

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